# FSL117MRIN Evaluation Board User's Manual

## **GENERAL BOARD DESCRIPTION**

FSL117MRIN Power Switch which is utilized in the evaluation board can be applied for home appliance applications. FSL117MRIN is an integrated Pulse–Width Modulation (PWM) controller and SENSEFET<sup>®</sup> specifically designed for high performance off–line SMPS. In order to minimize the power consumption in stand–by mode, the start up current source supplied by JFET is turned off during normal operation and the burst operation. Furthermore, A soft burst operation reduces audible noise during stand–by mode.

The board is designed to minimize the power consumption in stand-by mode and to have high efficiency in normal mode. The power stage has single output. It is a  $12 V_{OUT}$ .

#### Features of FSL117MRIN

- Advanced Burst Mode Operation for Low Stand-by Power
- Random Frequency Fluctuation for Low EMI
- Pulse-by-Pulse Current Limit
- Various Protection Functions: Overload Protection (OLP), Over-Voltage Protection (OVP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD) with Hysteresis, Output-Short Protection (OSP), Line Over-Voltage Protection (LOVP), and Under-Voltage Lock Out (UVLO) with Hysteresis
- Auto-Restart Mode
- Internal Start-up Circuit
- Internal High–Voltage SENSEFET (700 V)
- Built-in Soft Start: 15 ms



# **ON Semiconductor®**

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# EVAL BOARD USER'S MANUAL

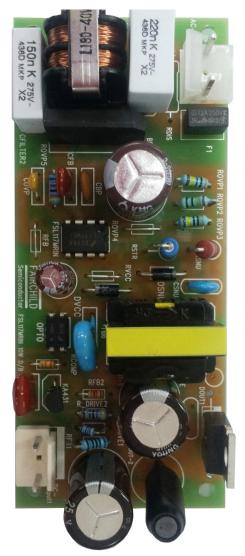


Figure 1. FSL117MRIN Evaluation Board

#### Block Diagram of FSL117MRIN

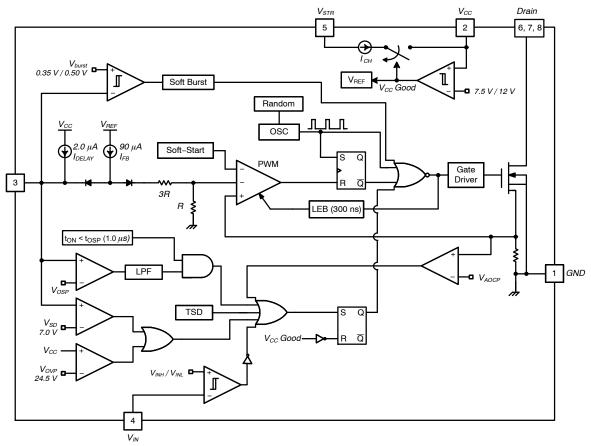


Figure 2. Block Diagram of FSL117MRIN

## Input-Output Specifications of the Evaluation Board

#### Table 1. INPUT-OUTPUT SPECIFICATIONS

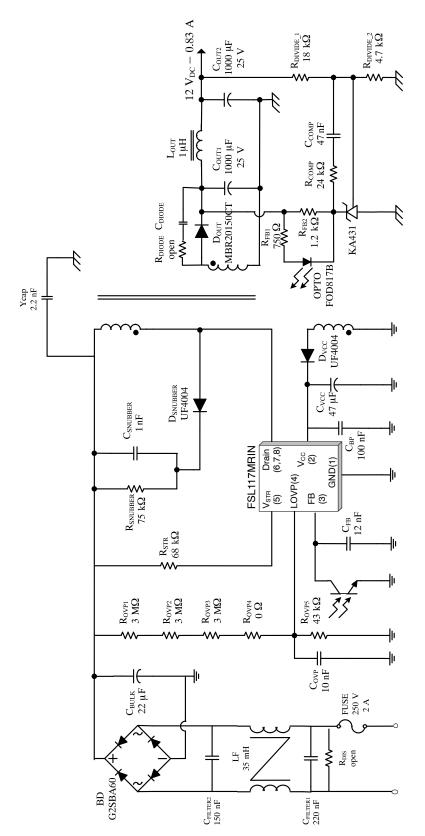
Description	Voltage	Current	Max Power
Input Voltage (V <sub>IN</sub> )	85~265 Vac 50~60 Hz	-	-
Output Voltage 1 (V <sub>OUT1</sub> )	12 Vdc	0.83 A	9.96 W (100%)
Total Output Power	-	-	9.96 W (100%)

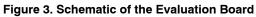
## Summary of Performance

## Table 2. SUMMARY OF PERFORMANCE

Symbol	Description	Value	Comments
P <sub>IN</sub> ,@0.000W P <sub>IN</sub> ,@0.120W P <sub>IN</sub> ,@0.240W P <sub>IN</sub> ,@0.360W P <sub>IN</sub> ,@0.480W	Stand-by Power (without discharge resistor / FSL117MRIN)	0.053 W 0.231 W 0.397 W 0.540 W 0.701 W	230 Vac input, P <sub>IN</sub> was averaged for 10 minutes
η85Vac η115Vac η230Vac η264Vac	Efficiency (η) P <sub>OUT</sub> = 23.0 W	Avg. 82.87% Avg. 84.38% Avg. 84.25% Avg. 83.53%	Average of 25, 50, 75 and 100% load (open frame, room temperature / still air)
T <sub>PKG,85</sub> Vac T <sub>PKG,115</sub> Vac T <sub>PKG,230</sub> Vac T <sub>PKG,264</sub> Vac	Temperature (FSD156MRBN)	69.0°C 57.9°C 52.3°C 54.7°C	Around Drain PIN of package surface of the IC @ full load (enclosed rectangular box)

Schematic of the Evaluation Board





## Photographs of Evaluation Board

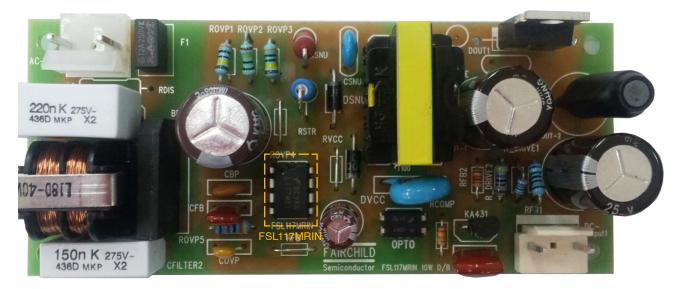


Figure 4. Top Side Photograph of the Evaluation Board

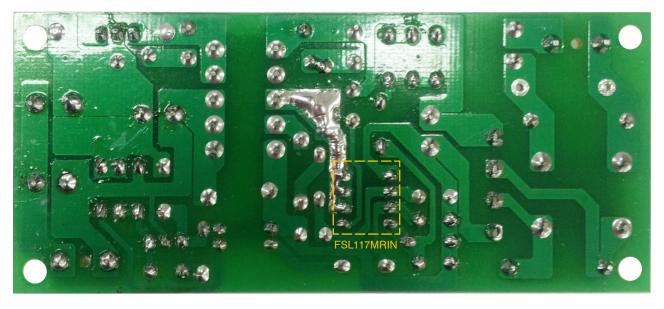


Figure 5. Bottom Side Photograph of the Evaluation Board

## **Bill of Materials**

The selected components for the evaluation board are shown in Table 3.

#### Table 3. BILL OF MATERIALS FOR EVALUATION BOARD

Part #	Value	Note	Part #	Value	Note
Fuse				Capacitor	
FUSE	250 V 2 A		CFILTER1	220 nF / 275 V	Box (Pilkor)
	Resistor		CFILTER2	150 nF / 275 V	Box (Pilkor)
RDIS	open		CBULK	22 μF / 400 V	Electrolytic (SamYoung)
ROVP1	3 MΩ	1%, 1/4 W	CSNUBBER	1 nF / 1 kV	film (sewha)
ROVP2	3 MΩ	1%, 1/4 W	CVCC	47 μF / 50 V	Electrolytic (KMG)
ROVP3	3 MΩ	1%, 1/4 W	CFB	12 nF / 100 V	film (sewha)
ROVP4	0 Ω	Jumper	CBP	100 nF	film (sewha)
ROVP5	43 kΩ	1%, 1/4 W	COVP	10 nF	film (sewha)
RSTR	68 kΩ	1 W	COUT1	1000 μF / 25 V	Electrolytic (SamYoung)
RSNUBBER	75 kΩ	1 W	COUT2	1000 μF / 25 V	Electrolytic (SamYoung)
RVCC	0 Ω	Jumper	CDIODE	open	
RFB	0 Ω	Jumper	CCOMP	47 nF	film (sewha)
RDIODE	open		YCAP	2.2 nF	film (sewha)
RFB1	750 Ω	1/4 W			
RFB2	1.2 kΩ	1/4 W		Inductor	
RCOMP	24 kΩ	1/4 W	LOUT	1 μH	
RDIVIDE1	18 kΩ	1%, 1/4 W	LF	35 mH	
RDIVIDE2	4 kΩ	1%, 1/4 W		Transformer	
<u> </u>	IC		T101	1 mH	EE2219
SMPS	FSL117MRIN	ON Semiconductor			
SHUNT	KA431LZ	ON Semiconductor			
OPTO	FOD817B	ON Semiconductor			
	Diode				
DSNUBBER	UF4004	Vishay			
DVCC	UF4004	Vishay			
DOUT	MBR20150CT	ON Semiconductor			
BD	G2SBA60	Vishay			

## **Transformer Specification**

- Core: EE2219 (Ae = 40.1 mm<sup>2</sup>)
- Bobbin: EE2219

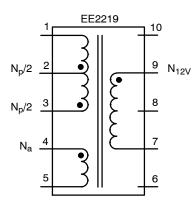


Figure 6. Transformer Specification

## Table 4. WINDING SPECIFICATION

						Barrier Tape	
	Pin(S → F)	Wire	Turns	Winding Method	ТОР	вот	Ts
N <sub>p</sub> /2 (BOT)	$3 \rightarrow 2$	0.25φ x 1	34	Solenoid winding	-	-	
Insulation: Polyester Tape t = 0.025 mm, 2 Layers							
N <sub>12V</sub>	$9 \rightarrow 7$	0.4φ x 2 (TIW)	12	Solenoid winding	-	-	
Insulation: Polyester Tape t = 0.025 mm, 2 Layers							
N <sub>a</sub>	$4 \rightarrow 5$	0.2φ x 1	14	Solenoid winding		-	
Insulation: Polyeste	er Tape t = 0.025 mm	, 2 Layers					
N <sub>p</sub> /2 (TOP)	$2 \rightarrow 1$	0.25φ x 1	33	Solenoid winding	-	-	
Insulation: Polyeste	er Tape t = 0.025 mm	, 2 Layers	-	-			

## Electrical Characteristics

#### Table 5. ELECTRICAL CHARACTERISTICS

	Pin	Spec	Remark
Inductance	$3 \rightarrow 1$	1.0 mH ±6%	67 kHz, 1 V

#### **PERFORMANCE DATA**

## Stand-by Power without AC Discharge Resistor

#### Table 6.

Test Condition	12 V <sub>OUT</sub>
Load	0.000 A~0.040 A
Output Power	0.000 W~0.480 W

#### Table 7. STAND-BY POWER

	FSL117MRIN			Pin	(W)	
Vo (V)	lo (A)	Po (W)	85 Vac	115 Vac	230 Vac	265 Vac
12	0.000	0.000	0.037	0.039	0.053	0.059
12	0.005	0.060	0.141	0.143	0.164	0.172
12	0.010	0.120	0.205	0.207	0.231	0.239
12	0.015	0.180	0.284	0.287	0.316	0.326
12	0.020	0.240	0.362	0.365	0.397	0.410
12	0.025	0.300	0.438	0.443	0.477	0.491
12	0.030	0.360	0.497	0.503	0.540	0.555
12	0.035	0.420	0.575	0.581	0.622	0.638
12	0.040	0.480	0.650	0.657	0.701	0.719

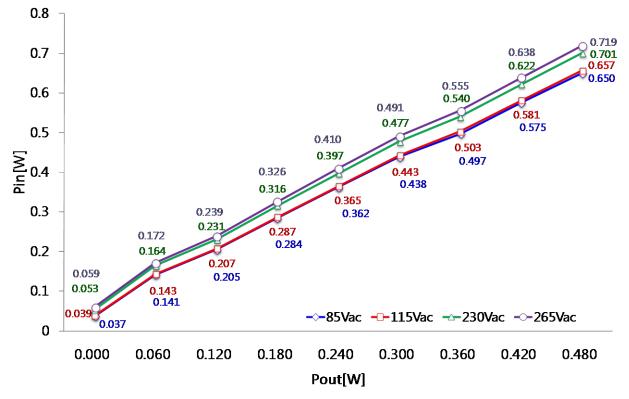
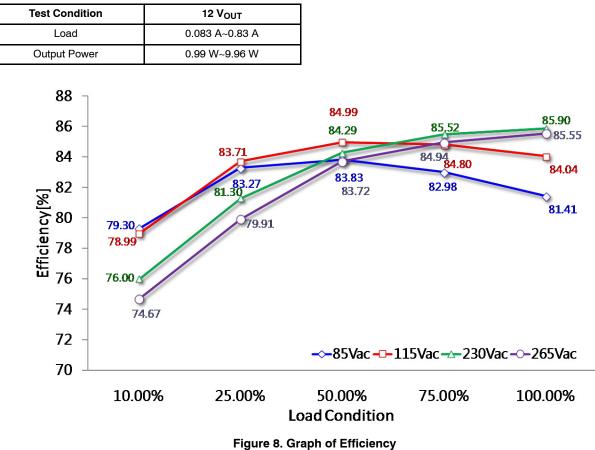


Figure 7. Graph of Standby Power

NOTE: Test results (PIN) were averaged for 10 minutes at each load

## Efficiency

Та	8.



	12	12.0 V				
Vin	lout [A]	Vout [V]	Pout [W]	Pin [W]	Efficiency [%]	Load
85 Vac	0.083	12.010	1.00	1.26	79.30	10.00%
	0.209	12.010	2.51	3.01	83.27	25.00%
	0.414	12.000	4.97	5.93	83.83	50.00%
	0.620	12.000	7.44	8.97	82.98	75.00%
	0.827	11.990	9.92	12.18	81.41	100.00%
	Ave	erage (25, 50, 75, 10	00%)		82.87	
115 Vac	0.083	12.010	1.00	1.26	78.99	10.00%
	0.209	12.010	2.51	3.00	83.71	25.00%
	0.414	12.000	4.97	5.85	84.99	50.00%
	0.620	12.000	7.44	8.77	84.80	75.00%
	0.827	11.990	9.92	11.80	84.04	100.00%
	Ave	erage (25, 50, 75, 10	00%)	•	84.38	
230 Vac	0.083	12.010	1.00	1.31	76.00	10.00%
	0.209	12.010	2.51	3.09	81.30	25.00%
	0.414	12.000	4.97	5.89	84.29	50.00%
	0.620	12.000	7.44	8.70	85.52	75.00%
	0.827	11.990	9.92	11.54	85.90	100.00%
	Ave	erage (25, 50, 75, 10	00%)		84.25	
265 Vac	0.083	12.010	1.00	1.34	74.67	10.00%
	0.209	12.010	2.51	3.14	79.91	25.00%
	0.414	12.000	4.97	5.93	83.72	50.00%
	0.620	11.990	7.43	8.75	84.94	75.00%
	0.827	11.990	9.92	11.59	85.55	100.00%
	Ave	erage (25, 50, 75, 10	00%)	•	83.53	

#### Table 9. EFFICIENCY OF THE EVALUATION BOARD

#### **EMI Test Result**

EMI Test Result at  $V_{IN} = 220$  Vac

#### Table 10.

Test Condition	12 V <sub>OUT</sub>
Load	0.8 A
Output Power	9.6 W

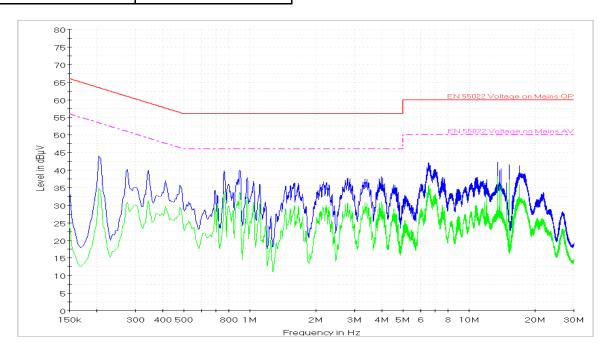
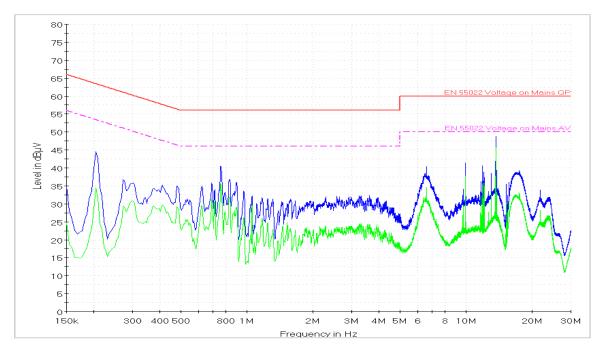
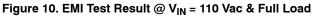


Figure 9. EMI Test Result @  $V_{IN}$  = 220 Vac & Full Load



*EMI Test Result at*  $V_{IN} = 110 Vac$ 



## **Thermal Characteristics**

Test Condition	12 V <sub>OUT</sub>	
Load	0.83 A	
Output Power	9.96 W	

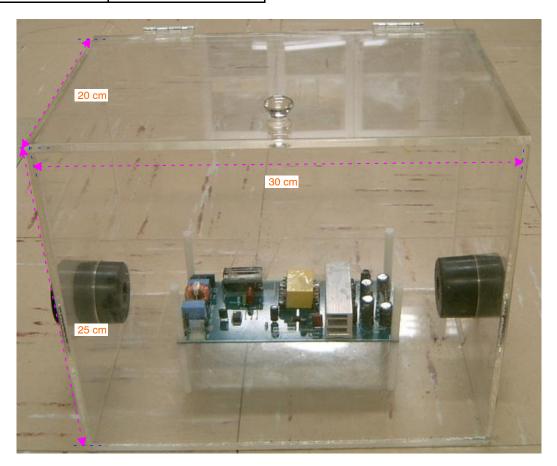


Figure 11. Rectangular Box

NOTE: Temperature of each component was measured in the rectangular box (Fig. 11)

# Temperature Measurement

Input Voltage	IC	Transformer	12 V Diode
85 Vac	69.0°C	44.5°C	55.1°C
115 Vac	57.9°C	44.7°C	55.4°C
230 Vac	52.3°C	46.2°C	55.7°C
265 Vac	54.7°C	47.1°C	55.5°C

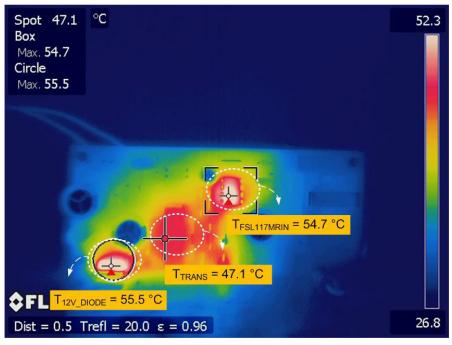


Figure 12. Thermal Cam @  $V_{\text{IN}}$  = 265 Vac & Full Load

Thermal Cam at V<sub>IN</sub> = 230 Vac, Full Load

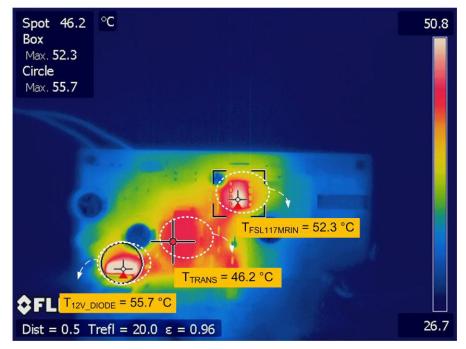


Figure 13. Thermal Cam @  $\rm V_{IN}$  = 230 Vac & Full Load

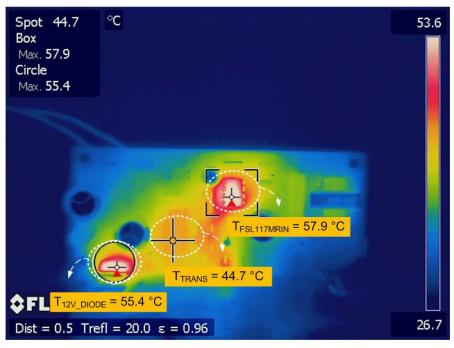


Figure 14. Thermal Cam @  $V_{\text{IN}}$  = 115 Vac & Full Load

Thermal Cam at  $V_{IN} = 85$  Vac, Full Load

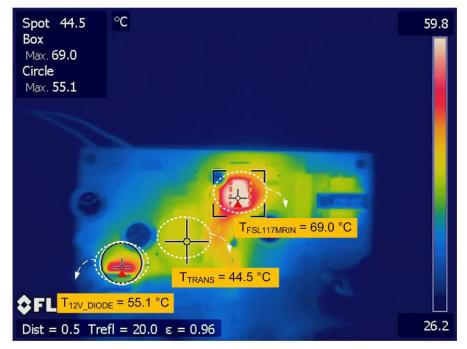


Figure 15. Thermal Cam @  $V_{\text{IN}}$  = 85 Vac & Full Load

## WAVEFORMS

#### Soft-Start

Table 13.

Test Condition	12 V <sub>OUT</sub>
Load	0.83 A
Output Power	9.96 W

Soft-Start at V<sub>IN</sub> = 85 Vac, Full Load

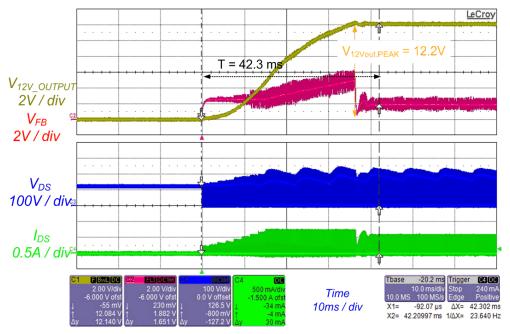
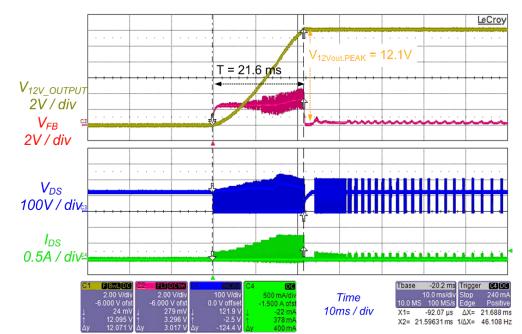


Figure 16. Soft-Start Waveforms @ V<sub>IN</sub> = 85 Vac & Full Load



*Soft–Start at V<sub>IN</sub> = 90 Vac, No Load* 



#### Soft-Start at V<sub>IN</sub> = 265 Vac, Full Load

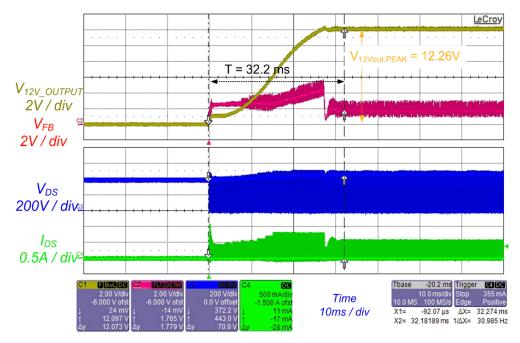


Figure 18. Soft-Start Waveforms @ VIN = 265 Vac & Full Load

Soft-Start at V<sub>IN</sub> = 265 Vac, No Load

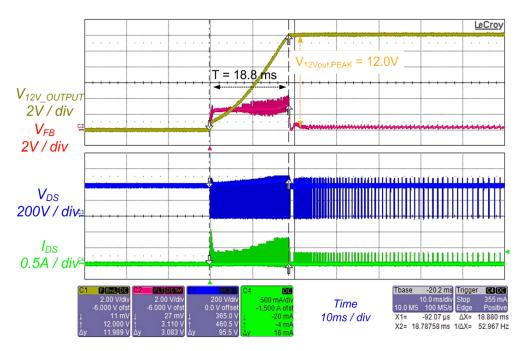


Figure 19. Soft-Start Waveforms @ VIN = 265 Vac & No Load

#### Start-up

#### Table 14.

Test Condition	12 V <sub>OUT</sub>
Load	0.83 A
Output Power	9.96 W

Start-up at V<sub>IN</sub> = 85 Vac, Full Load

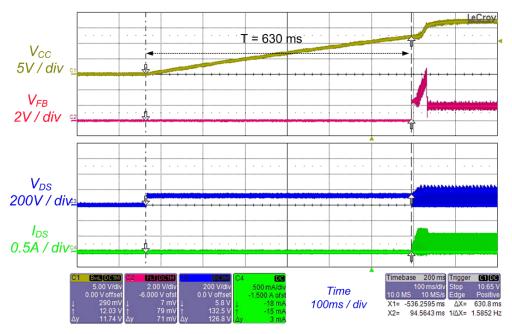


Figure 20. Start-up Waveforms @ V<sub>IN</sub> = 85 Vac & Full Load

*Start–up at V\_{IN} = 85 Vac, No Load* 

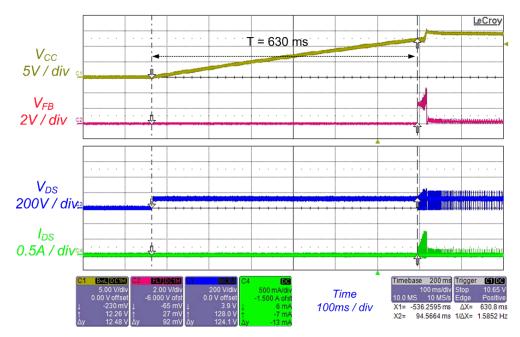


Figure 21. Start-up Waveforms @ V<sub>IN</sub> = 85 Vac & No Load

## *Start–up at V<sub>IN</sub> = 265 Vac, Full Load*

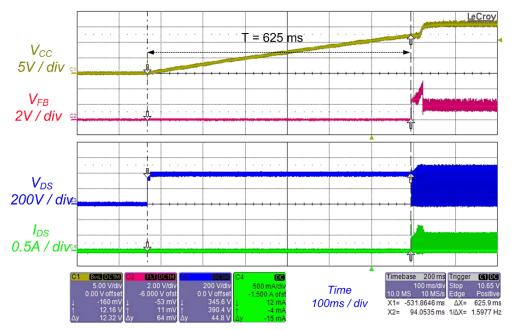


Figure 22. Start-up Waveforms @ V<sub>IN</sub> = 265 Vac & Full Load

*Start–up at V<sub>IN</sub> = 265 Vac, No Load* 

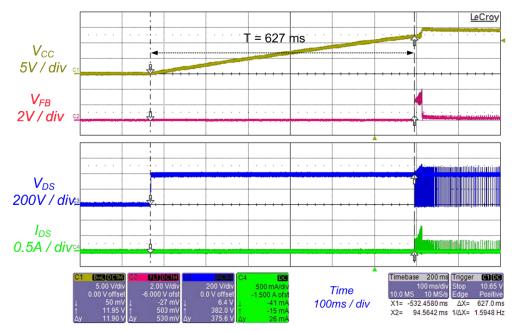


Figure 23. Start-up Waveforms @ V<sub>IN</sub> = 265 Vac & No Load

#### **Normal Operation**

#### Table 15.

Test Condition	12 V <sub>OUT</sub>
Load	0.83 A
Output Power	9.96 W

Normal Operation at  $V_{IN} = 85 Vac$ 

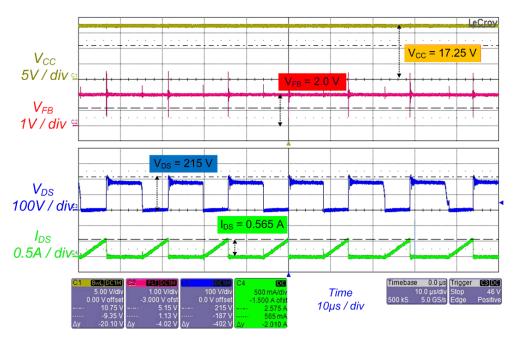
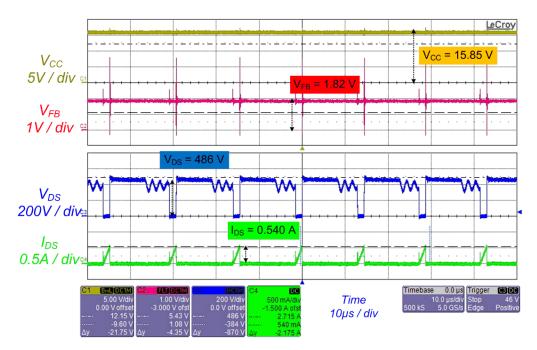


Figure 24. Normal Operation @ V<sub>IN</sub> = 85 Vac & Full Load

*Normal Operation at*  $V_{IN} = 265 Vac$ 





#### **Burst Operation**

#### Table 16.

Test Condition	12 V <sub>OUT</sub>
Load	No Load
Output Power	0 W

Burst Operation at  $V_{IN} = 85 Vac$ 

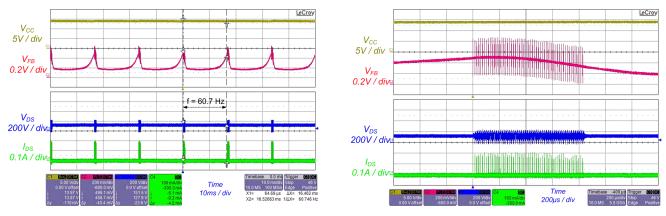


Figure 26. Burst Operation @ V<sub>IN</sub> = 85 Vac, No Load

Burst Operation at  $V_{IN} = 85$  Vac

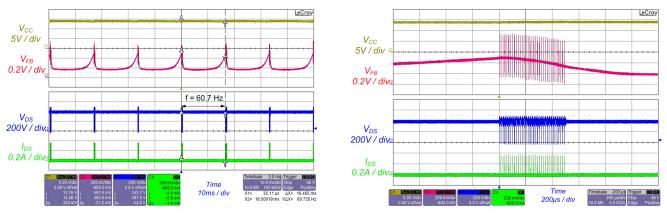
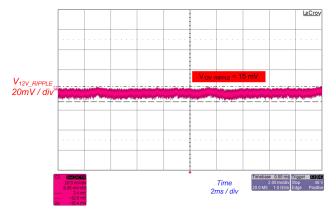


Figure 27. Burst Operation @ V<sub>IN</sub> = 265 Vac, No Load

#### **Output Voltage Ripple**

Table 17.	
Test Condition	12 V <sub>OUT</sub>
100% load	0.83 A
75% load	0.62 A
50% load	0.41 A
25% load	0.20 A
0% load	0 A

# 12 V Output Voltage Ripple at $V_{IN}$ = 85 Vac



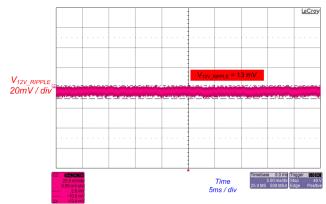


Figure 28. 12 V Ripple @ V<sub>IN</sub> = 85 Vac, 100% Load

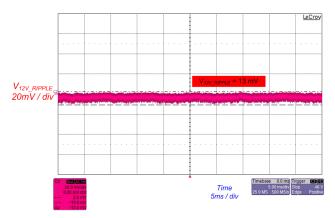


Figure 30. 12 V Ripple @  $V_{IN}$  = 85 Vac, 50% Load

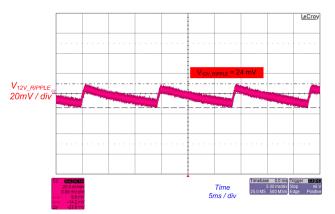


Figure 32. 12 V Ripple @ V<sub>IN</sub> = 85 Vac, 0% Load

Figure 29. 12 V Ripple @  $V_{IN}$  = 85 Vac, 75% Load

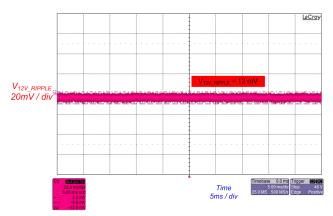
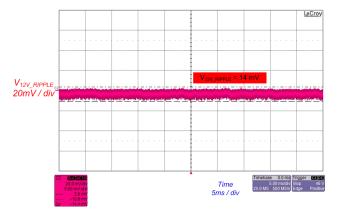


Figure 31. 12 V Ripple @  $V_{IN}$  = 85 Vac, 25% Load

# 12 V Output Voltage Ripple at V<sub>IN</sub> = 115 Vac



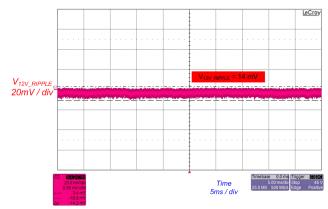


Figure 34. 12 V Ripple @ V<sub>IN</sub> = 115 Vac, 75% Load

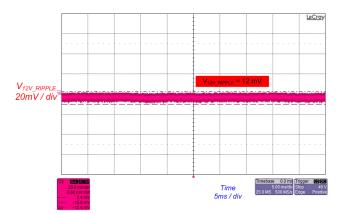


Figure 36. 12 V Ripple @  $V_{IN}$  = 115 Vac, 25% Load

Figure 33. 12 V Ripple @ V<sub>IN</sub> = 115 Vac, 100% Load

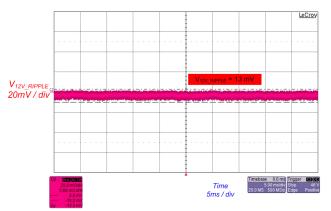


Figure 35. 12 V Ripple @  $V_{IN}$  = 115 Vac, 50% Load

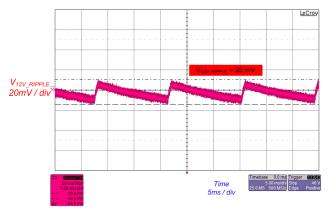
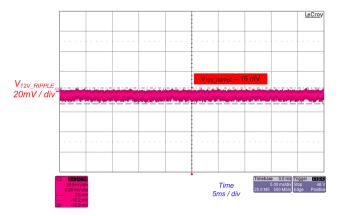


Figure 37. 12 V Ripple @  $V_{IN}$  = 115 Vac, 0% Load

12 V Output Voltage Ripple at V<sub>IN</sub> = 230 Vac



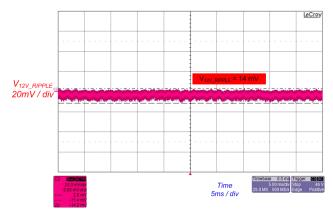


Figure 39. 12 V Ripple @  $V_{IN}$  = 230 Vac, 75% Load

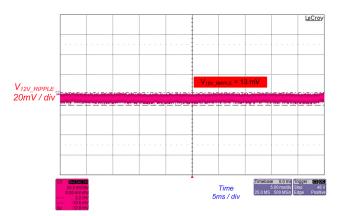


Figure 41. 12 V Ripple @  $V_{IN}$  = 230 Vac, 25% Load

Figure 38. 12 V Ripple @ V $_{\rm IN}$  = 230 Vac, 100% Load

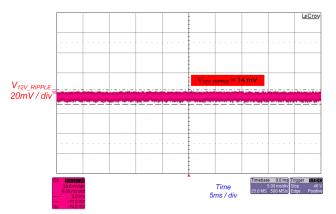


Figure 40. 12 V Ripple @ V<sub>IN</sub> = 230 Vac, 50% Load

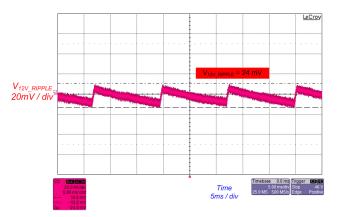
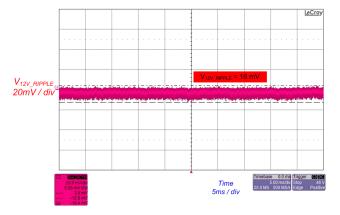


Figure 42. 12 V Ripple @ V<sub>IN</sub> = 230 Vac, 0% Load

# 12 V Output Voltage Ripple at V<sub>IN</sub> = 265 Vac



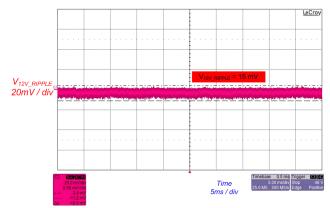


Figure 44. 12 V Ripple @  $V_{IN}$  = 265 Vac, 75% Load

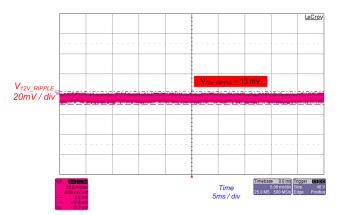


Figure 46. 12 V Ripple @  $V_{IN}$  = 265 Vac, 25% Load

Figure 43. 12 V Ripple @ V<sub>IN</sub> = 265 Vac, 100% Load

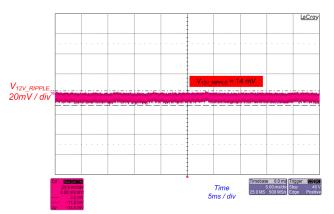


Figure 45. 12 V Ripple @  $V_{IN}$  = 265 Vac, 50% Load

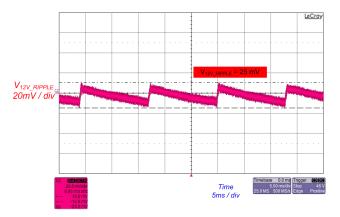
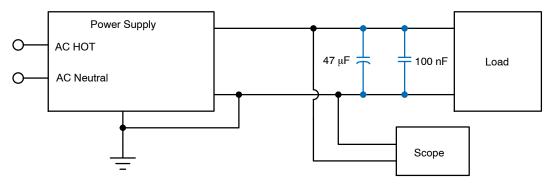


Figure 47. 12 V Ripple @  $V_{IN}$  = 265 Vac, 0% Load

- Measure with additional capacitors (47  $\mu F$  electrolytic and 100 nF mono) on 5  $V_{OUT}\,PCB$
- Oscilloscope bandwidth: 20 MHz

#### Table 18. OUTPUT RIPPLE VOLTAGE

	85 Vac	110 Vac	230 Vac	265 Vac	
Load	12 V Ripple	12 V Ripple	12 V Ripple	12 V Ripple	Unit
100%	15	14	16	16	mV
75%	13	14	14	15	
50%	13	13	14	14	
25%	12	12	13	13	
0%	24	25	24	25	



NOTES:

1. Load the output with its maximum load current

- 2. Connect the probes as shown
- 3. Repeat the measurement with standby load on the output

#### Figure 48.

#### **Output Voltage Regulation**

#### Table 19. OUTPUT VOLTAGE REGULATION

				Load		
VIN	νουτ	100%	75%	50%	25%	No Load
265 Vac	12 V <sub>OUT</sub>	-0.08%	0.00%	0.08%	0.17%	0.17%
230 Vac		-0.08%	0.00%	0.08%	0.17%	0.17%
115 Vac		0.00%	0.00%	0.08%	0.17%	0.17%
85 Vac		0.00%	0.00%	0.08%	0.17%	0.17%

## Short Test

12 V Output Overload at V<sub>IN</sub> = 85 Vac

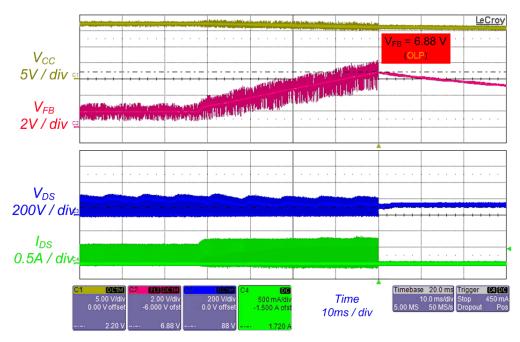
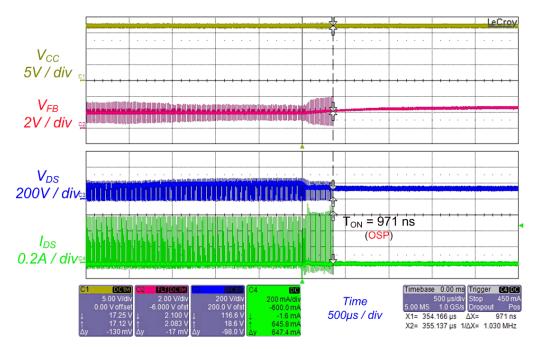


Figure 49. 12 V Output Overload @ V<sub>IN</sub> = 85 Vac, Full Load

12 V Output Voltage Short at V<sub>IN</sub> = 85 Vac





12 V Output Voltage Short at V<sub>IN</sub> = 265 Vac

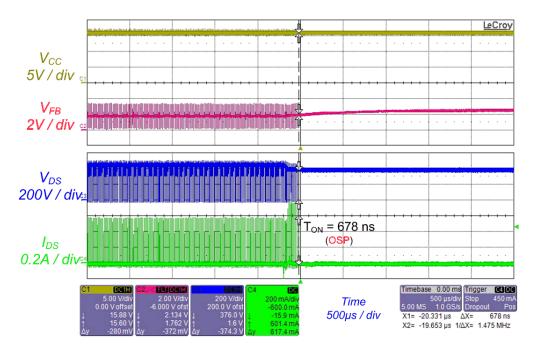
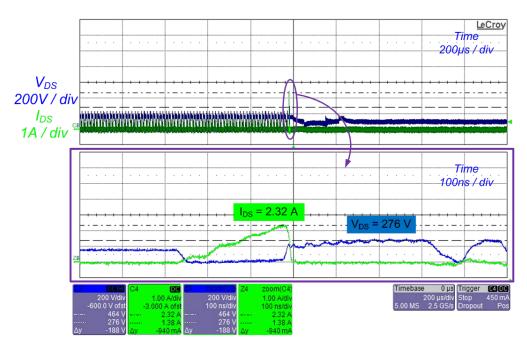


Figure 51. 12 V Output Voltage Short @  $V_{IN}$  = 265 Vac, Full Load

12 V Output Diode Short at  $V_{IN} = 85$  Vac





# 12 V Output Diode Short at V<sub>IN</sub> = 265 Vac

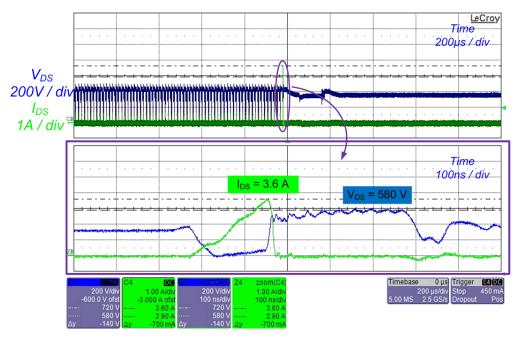
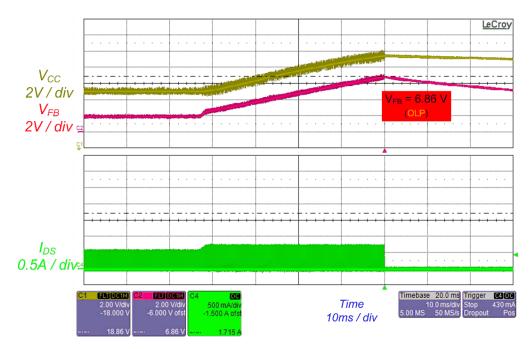


Figure 53. 12 V Output Diode Short @  $V_{IN}$  = 265 Vac, Full Load

 $2^{nd} Opto-coupler Short at V_{IN} = 85 Vac$ 







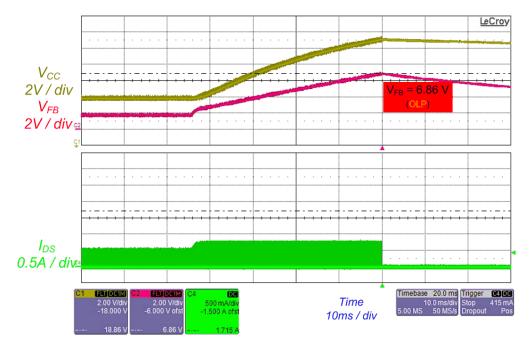
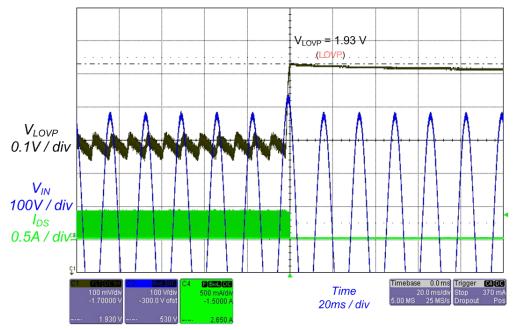
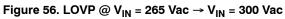


Figure 55. 2nd Opto Short @  $V_{IN}$  = 265 Vac, Full Load

## LOVP (Line Over Voltage Protection) Test

LOVP at  $V_{IN} = 265 Vac \rightarrow V_{IN} = 300 Vac$ 





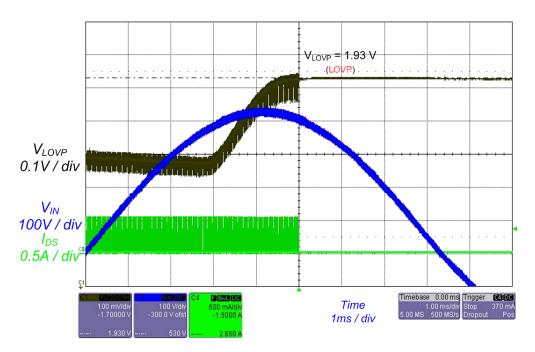
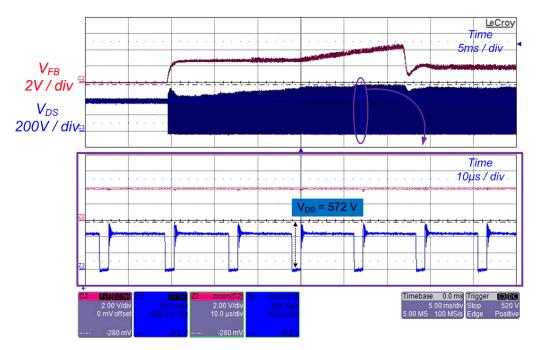


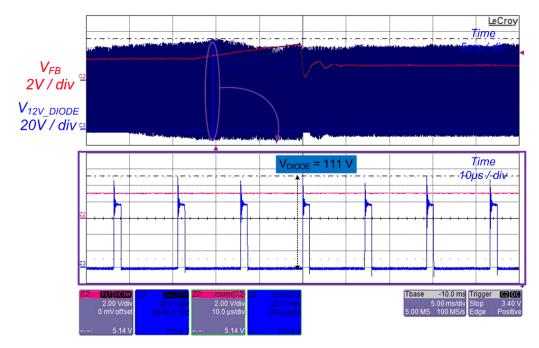
Figure 57. LOVP @ V<sub>IN</sub> = 265 Vac  $\rightarrow$  V<sub>IN</sub> = 300 Vac, Enlarge

# Voltage Stress of Secondary Diode and Drain

Voltage Stress of Drain at V<sub>IN</sub> = 265 Vac, Full Load







Voltage Stress of  $2^{nd}$  Diode at  $V_{IN} = 265$  Vac , Full Load

Figure 59. Diode Voltage @  $V_{\text{IN}}$  = 265 Vac, Full Load

# TRANSFORMER DESIGN USING DESIGN TOOL

Minimum Line voltage (V <sub>line</sub> <sup>min</sup> )	85	V,n	ms				
Maximum Line voltage (V <sub>line</sub> <sup>max</sup> )	280						
Line frequency (f <sub>L</sub> )		Hz				-	
						-	
	V <sub>o(n)</sub>		I <sub>0(n)</sub>		P <sub>o(n)</sub>		KL
1st output for feedback	12	V.	0,80	A	<u>10</u>	W	1
2nd output		V	0,00		<u>0</u>	W	
3rd output	0	<u>V</u>	0,00		0	W	
4th output 5th output	0	V V	0,00		0 0 0 0	W	
6th output	Ŭ	v	0,00	Â	ŏ	ŵ	
Maximum output power (P <sub>o</sub> ) =	<u>9,6</u>	w					
Estimated efficiency (E <sub>ff</sub> )	80						
Maximum input power (P <sub>in</sub> ) =	12.0						
Determine DC link capacitor and DC link v	oltage ran	ge					
DC link capacitor (C <sub>DO</sub> )	22	uF					
Minimum DC link voltage (V <sub>DC</sub> <sup>min</sup> ) =	<u>85</u>	V.					
Maximum DC link voltage (V <sub>DC</sub> <sup>max</sup> )=	<u>396</u>	V.					
Determine Maximum duty ratio (Dmax)							
Maximum duty ratio (D <sub>max</sub> )	0,45						
Max nominal MOSFET voltage (V <sub>ds</sub> <sup>nom</sup> ) =	<u>465</u>	V.					
Output voltage reflected to primary (V <sub>RO</sub> )=	<u>69</u>	V.					
	(1 X		k		1 (DCM)		
Determine transformer primary inductance (		1.1.1			1 (CCM)		
Switching frequency of FPS (f₅)		kHz					
Ripple factor (K <sub>RF</sub> )	0,91		<b>A</b> 7			1	
Primary side inductance (L <sub>m</sub> ) =	<u>1008</u>			/		T	
Maximum peak drain current (I <sub>ds</sub> <sup>peak</sup> ) =		Α	<b>'</b> (	<i>c</i>			
RMS drain current (I <sub>ds</sub> <sup>rms</sup> ) =	<u>0,24</u>	Α		Kpr	$r = \frac{\Delta I}{2I_{EDC}}$		
Maximum DC link voltage in CCM (V <sub>DC</sub> <sup>CCM</sup> )	<u>94</u>	۷		A.	21 <sub>EDC</sub>		
Choose the proper FPS considering the in	nut nower	0.0		ant li	mit		_
Typical current limit of FPS (I <sub>over</sub> )		an A	u cum	ent l	mile		
Minimum I <sub>over</sub> considering tolerance of 12%		A	>	0.6	:	Α	
Minimum lover considering tolerance of 12%	0.70	H .		10.0	0	A.	

Figure 60.

Determine the proper core and the minim			IS				
Saturation flux density (B <sub>sat</sub> )		Т	<u> </u>				
Cross sectional area of core (A <sub>e</sub> )	40,1	mm	2				
Minimum primary turns (N <sub>p</sub> <sup>min</sup> )=	<u>62.9</u>	Т					
Determine the number of turns for each	output						
Determine the number of turns for each	σατρατ						
	V <sub>o(n)</sub>		V <sub>F(n)</sub>			ŧ	of tur
Vcc (Use Vcc start voltage)	14	٧	0,5	V	13,9	⇒	
1st output for feedback	<u>12</u>	V.	0,5		12		1
2nd output		٧		٧	<u>0.0</u>	=>	
3rd output	0	V.	0	٧	0.0	$ \ge $	
4th output		٧	0	٧	0.0	=>	
5th output		٧	0	V		$\equiv >$	
6th output		٧		V		$\equiv >$	
VF : Forward voltage drop of rectifier diode			Primar	y ti	urns (N <sub>e</sub>	)=	<u>6</u>
					ugh turns		
Ungapped AL value (AL)	840	nH.			n	=	5,54
Gap length (G) ; center pole gap =	0,1612						0,04
aup lengui (a) / center pore gap -	0,1012		•				
Determine the wire diameter for each wir	ndina						
	Diameter		Parall	el	l <sub>D(n)</sub> rms	()	√mm <sup>3</sup>
Primary winding	0,25		1	Т	I <sub>D(n)</sub> rma <u>0,2</u>	А	4.9
Vcc winding	0,25 0,2	mm	1 1	T T	<u>0.2</u> <u>0.7</u>	A A	<u>4.9</u> 22.3
Vcc winding 1st output winding (12V)	0,25	mm	1 1 2	T T T	0.2 0.7 1.5	A A A	<u>4.9</u> 22.3 5.8
Vcc winding	0,25 0,2 0,4	mm	1 1 2 0	T T T T	0.2 0.7 1.5	A A	<u>4.9</u> 22.3 5.8
Vcc winding 1st output winding (12V)	0,25 0,2 0,4 0	mm mm	1 1 2 0	T T T T	0.2 0.7 1.5	A A A	<u>4.9</u> 22.3 5.8 ####
Vcc winding 1st output winding (12V) 2nd output winding (0V)	0,25 0,2 0,4 0 0	mm mm mm	1 1 2 0 0	T T T T	0.2 0.7 1.5 #####	A A A	4.9 22.3 5.8 #### #### ####
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V)	0,25 0,2 0,4 0 0 0	mm mm mm mm	1 1 2 0 0 0	T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V)	0,25 0,2 0,4 0 0 0	mm mm mm mm	1 1 2 0 0 0	T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V)	0,25 0,2 0,4 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V)	0,25 0,2 0,4 0 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area (A <sub>c</sub> ) =	0,25 0,2 0,4 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$ Required window area $(A_{wr})$	0,25 0,2 0,4 0 0 0 0 0 0 0 5,72 0,15 44,79	mm mm mm mm mm mm	1 2 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$	0,25 0,2 0,4 0 0 0 0 0 0 0 5,72 0,15 44,79	mm mm mm mm mm mm	1 2 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$ Required window area $(A_{wr})$	0,25 0,2 0,4 0 0 0 0 0 0 0 5,72 0,15 44,79	mm mm mm mm mm mm	1 2 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$ Required window area $(A_{wr})$ Choose the rectifier diode in the second Vcc diode	0,25 0,2 0,4 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### ##### ##### #####	A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$ Required window area $(A_{wr})$ Choose the rectifier diode in the second Vcc diode Rectifier diode for 1st output (12V)	0,25 0,2 0,4 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### ##### ##### Jun 10	A A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$ Required window area $(A_{wr})$ Choose the rectifier diode in the second Vcc diode	0,25 0,2 0,4 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0 1 <sup>2</sup> 1 <sup>2</sup>	T T T T T T	0,2 0,7 1,5 ##### ##### ##### ##### ##### Jun D(n) 0,10 1,46	A A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$ Required window area $(A_{wr})$ Choose the rectifier diode in the second Vcc diode Rectifier diode for 1st output (12V)	0,25 0,2 0,4 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### ##### ##### Junnon 0.10 1.46	A A A A A A A A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area ( $A_c$ ) = Fill factor ( $K_F$ ) Required window area ( $A_{wr}$ ) Choose the rectifier diode in the second Vcc diode Rectifier diode for 1st output (12V) Rectifier diode for 2nd output (0V)	0,25 0,2 0,4 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### ##### ##### Junce Interimental In	A A A A A A A A A A A A A A A	<u>4.9</u> <u>22.3</u> <u>5.8</u> <u>####</u> <u>####</u> <u>####</u> <u>####</u>
Vcc winding 1st output winding (12V) 2nd output winding (0V) 3rd output winding (0V) 4th output winding (0V) 5th output winding (0V) 6th output winding (V) Copper area $(A_c) =$ Fill factor $(K_F)$ Required window area $(A_{wr})$ Choose the rectifier diode in the second Vcc diode Rectifier diode for 1st output (12V) Rectifier diode for 2nd output (0V) Rectifier diode for 3rd output (0V)	0,25 0,2 0,4 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	mm mm mm mm mm mm	1 2 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	T T T T T T	0.2 0.7 1.5 ##### ##### ##### ##### 0,10 1.46 ##### #####	A A A A A A A A A A A A A A A A A	/mm <sup>2</sup> 22.3 5.8 #### #### #### #### ####

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